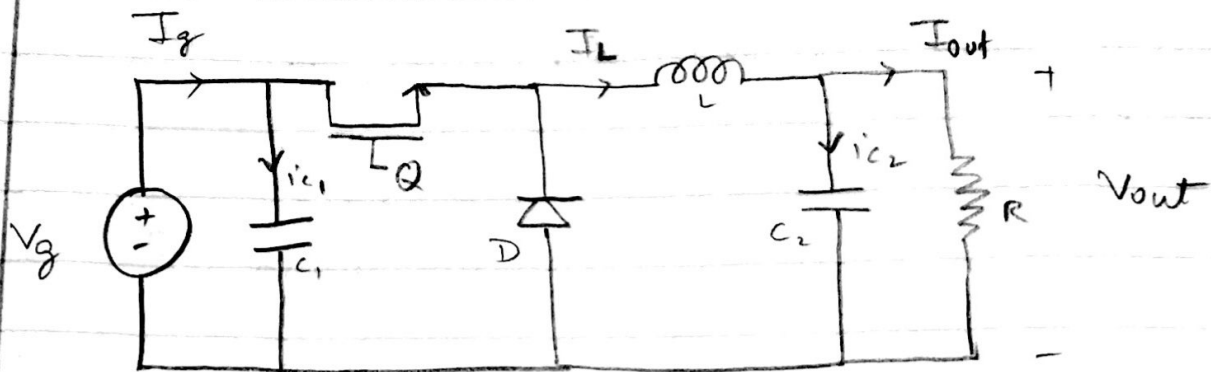


Date: 1-28-2017

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Pre lab - Exp - 3-1

Convenient operating point for design



$$V_g = 17.2 \text{ V}$$

$$V_{out} = 13 \text{ V}$$

$$D_{max} = 0.755$$

$$P_{out} = 85 \text{ W} \Rightarrow I_{out} = 6.538 \text{ A} = I_L$$

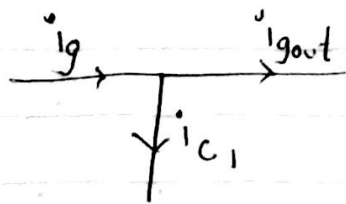
$$I_g = 0.755 I_L \\ = 4.936 \text{ A}$$

Assuming 12% ripple and $f_s = 25 \text{ kHz}$

$$\Delta I = 0.7845 \text{ A}$$

1. Current waveforms of power components

Input filter capacitor C_1

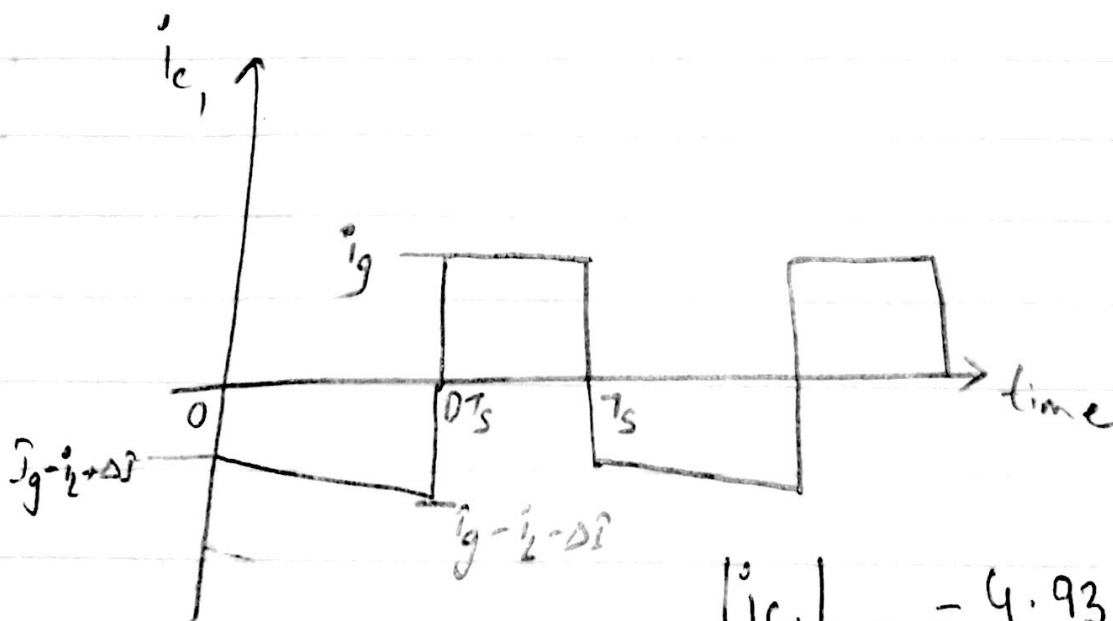


Switch on

$$i_{c1} = I_g - i_{gout}$$

Switch OFF

$$i_{c1} = I_g$$



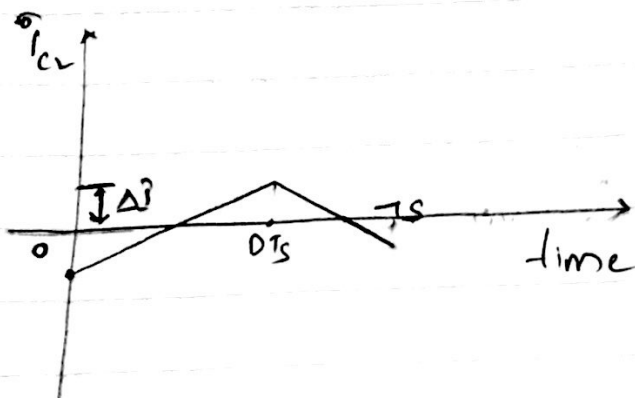
$$|i_{c1}|_{\max} = 4.936 \text{ A}$$

$$i_{c1 \min} = -2.3925 \text{ A}$$

$$i_{c1 \text{ rms}} = 0.2088 \text{ A}$$

Output capacitor filter C_L

-the current in output capacitor will be ripple of inductor

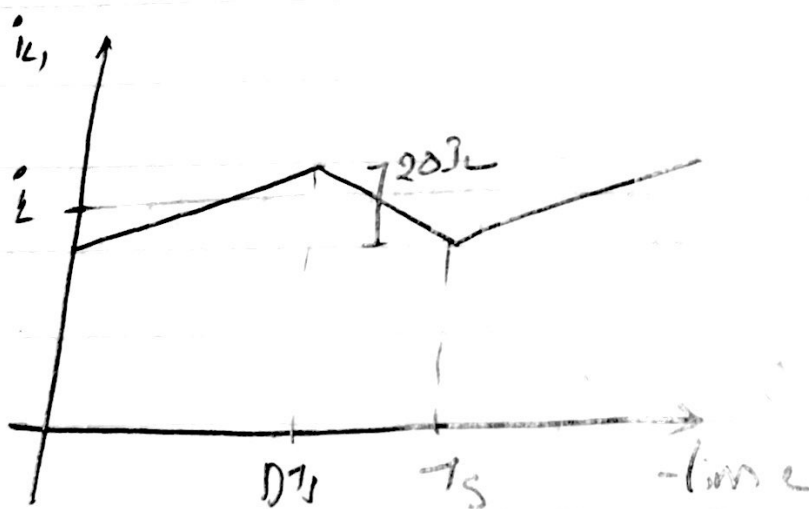


$$i_{C_L \max} = 0.7845 \text{ A}$$

$$i_{C_L \min} = -0.7845 \text{ A}$$

$$i_{C_L \text{ rms}} = 0.4529 \text{ A}$$

Inductor L_1

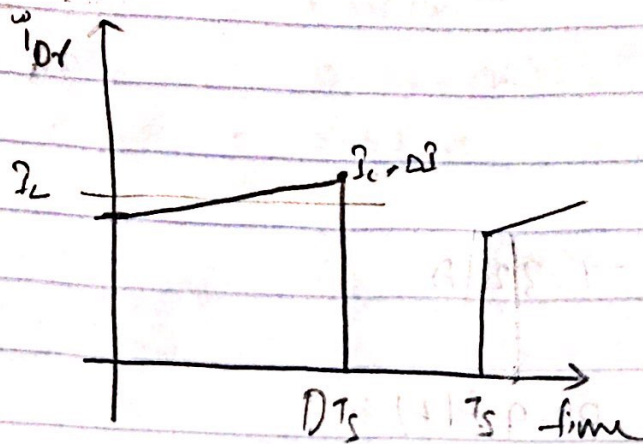


$$i_{L_1 \max} = 7.322 \text{ A}$$

$$i_{L_1 \min} = 5.753 \text{ A}$$

$$i_{L_1 \text{ rms}} = 6.5 \text{ A}$$

Mosfet Drain Current

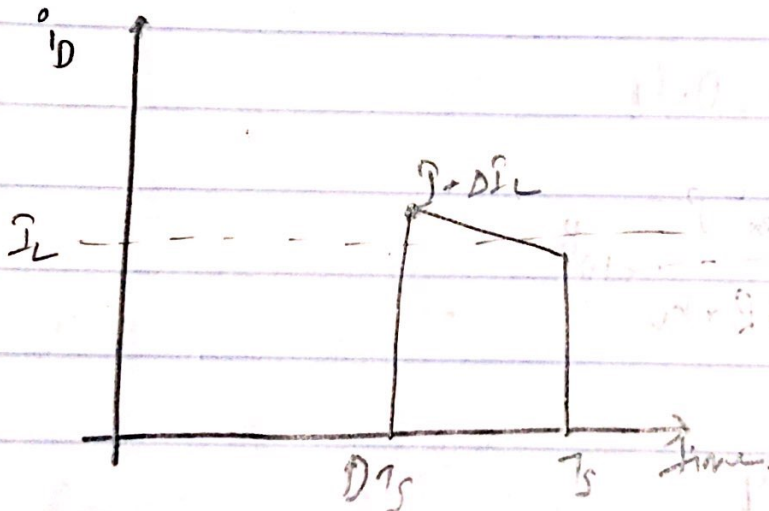


$$i_{D \max} = 7.322 \text{ A}$$

$$i_{D \min} = 0 \text{ A}$$

$$i_{D \text{ avg}} = 5.694 \text{ A}$$

Diode Current



$$i_{D \max} = 7.322 \text{ A}$$

$$i_{D \min} = 0$$

$$i_{D \text{ avg}} = 3.24 \text{ A}$$

2. Inductor design

$$f_s = 25 \text{ kHz}$$

$$D = 0.755$$

$$\Delta I = 12\%$$

$$I_{\max} = I_L + \Delta I = 7.32 \text{ A}$$

$$L = \frac{V_{out} D' T_s}{2 \Delta I} = 80.9 \mu\text{H}$$

$$P_{\text{loss}} = 1 \text{ W} \Rightarrow R = 23.4 \text{ m}\Omega$$

$$B_{\max} = 0.25 \text{ T}$$

$$\text{fill factor } k_u = 0.4$$

$$k_g \geq \frac{L^2 I_{\max}^2 \rho}{B_{\max}^2 \times R \times k_u} \times 10^8$$

$$k_g \geq 0.104$$

A ferrite PQ 26/25 with $k_g = 0.125 \text{ cm}^5$ is selected

from PO 26/25 data sheet

$$A_c = 1.18 \text{ cm}^2$$

$$C_{VA} = 0.503 \text{ cm}^2$$

$$MLT = 5.62 \text{ cm}$$

$$\text{air gap } l_g = \frac{\mu_0 \times L \times I_{max}^2}{B_{max}^2 \times A_c} \times 10^4$$

$$l_g = 0.739 \text{ mm}$$

$$\text{Number of turns : } N = \frac{L \times I_{max} \times 10^4}{B_{max} \times A_c}$$

$$N = 20.1$$

$$A_w \leq \frac{k_u W_A}{N_1} \Rightarrow A_w \leq \text{~~10 \times 10^3~~}$$

$$A_w \leq 10 \times 10^3 \text{ cm}^2$$

Use

AWG #18

3. Balance of conversion

MosFET : HUF75321

rated : 55V, 35A

Voltage and current stress expected = 205V, 7.32A

well within specs.

Diode : MBR1645

rated : 45V, 16A

Voltage and current stress expected = 14.4V, 7.32A

well within specs.

Capacitor $C_1 = 3300 \mu F$

Rating : $75V, 4.22A_{rms}$

Voltage and current shown expected : $20V, 2.8A$

well within spec

Capacitor $C_2 = 730 \mu F$

Rating : $25V, 0.865A_{rms}$

Voltage and current shown expected : $14.4V, 0.42A$

well within spec